

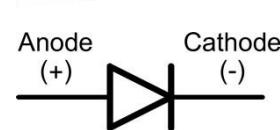
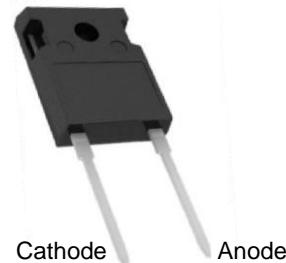
F2CD10170P

1700V Silicon Carbide Diode

Features

- 1700-Volt Schottky Rectifier
- Shorter recovery time
- High-speed switching possible
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on VF
- RoHS Compliant

Package Outline



TO-247_2L

Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor Drives
- HID Lighting

Absolute Maximum Ratings

T_C = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{RRM}	Repetitive Peak Reverse Voltage	1700	V
V _{RSM}	Surge Peak Reverse Voltage	1700	V
V _{DC}	DC Blocking Voltage	1700	V
I _F	Continuous Forward Current T _C = 25°C T _C = 160°C	36 10	A
I _{FRM}	Repetitive Peak Forward Current T _C = 110°C	83	A
I _{FSM}	Non-Repetitive Forward Surge Current T _C = 25°C (PW=10ms sinusoidal) T _C = 110°C	60 50	A
P _D	Power Dissipation T _C = 25°C	214	W
T _J , T _{Stg}	Operating Junction and Storage Temperature	-55 to +175	°C

**Electrical Characteristics** $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
V_F	Forward Voltage	$I_F = 10\text{A}, T_C = 25^\circ\text{C}$ $I_F = 10\text{A}, T_C = 175^\circ\text{C}$	--	1.5 2.0	1.8 2.4	V
I_R	Reverse Current	$V_R = 1700\text{V} T_C = 25^\circ\text{C}$ $V_R = 1700\text{V} T_C = 175^\circ\text{C}$	--	5 20	100 -	uA
Q_C	Total Capacitive Charge	$V_R = 1200\text{V}$	--	101	--	nC
C	Total Capacitance	$V_R = 1\text{V}, T_J = 25^\circ\text{C}, f = 1\text{MHz}$ $V_R = 1200\text{V}, T_J = 25^\circ\text{C}, f = 1\text{MHz}$	--	682 53	--	pF

Thermal Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Min	Typ	Max	Units
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	--	0.7	0.84	°C/W

Typical Characteristics

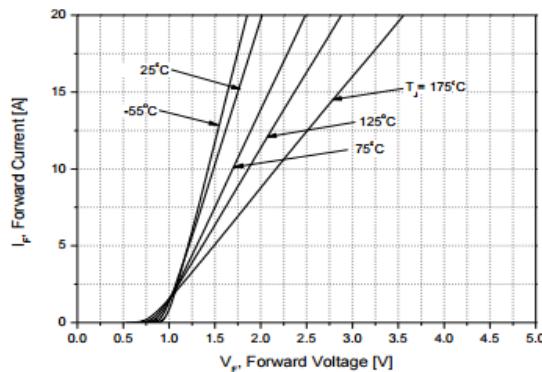


Figure 1. Forward Characteristics

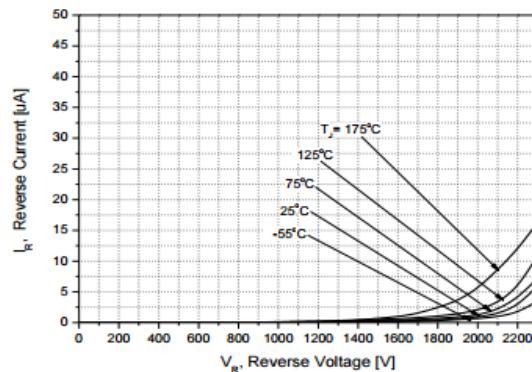


Figure 2. Reverse Characteristics

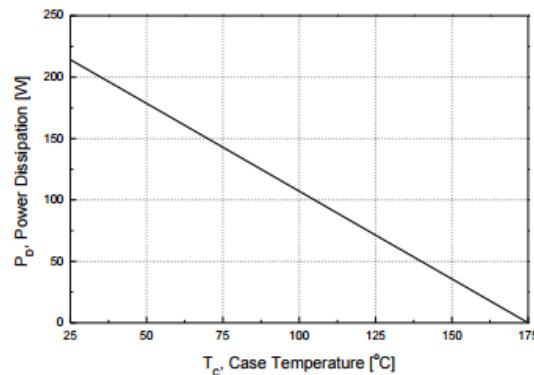


Figure 3. Power Dissipation

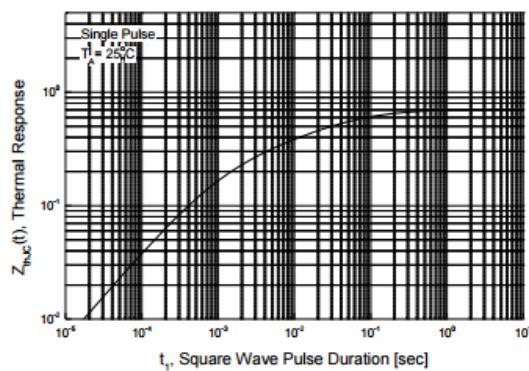


Figure 4. Transient Thermal Resistance

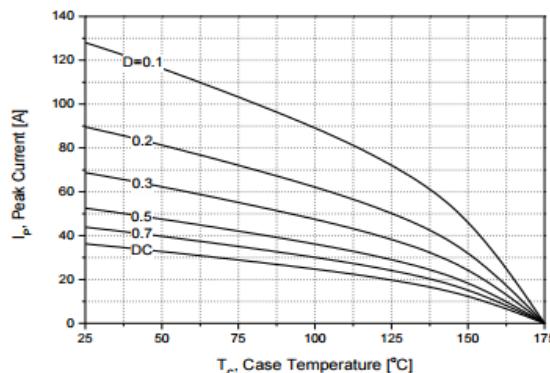


Figure 5. Peak Forward Current Derating

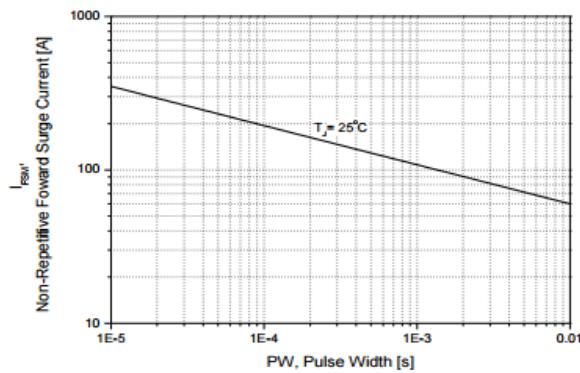


Figure 6. Non-Repetitive Peak Forward Surge Current vs. Pulse Duration

Typical Characteristics

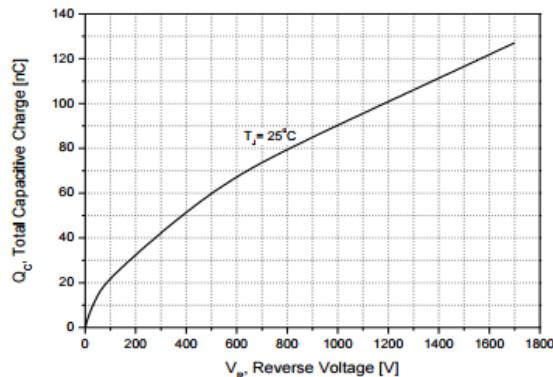


Figure 7. Total Capacitive Charge

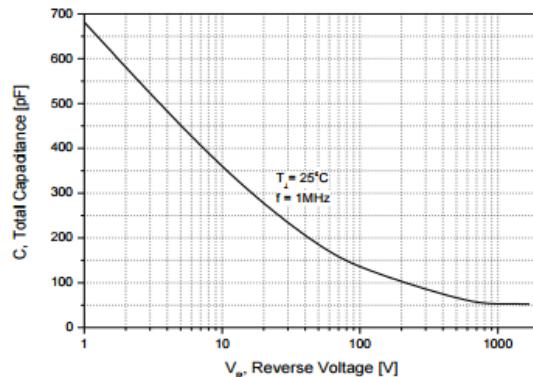


Figure 8. Total Capacitance

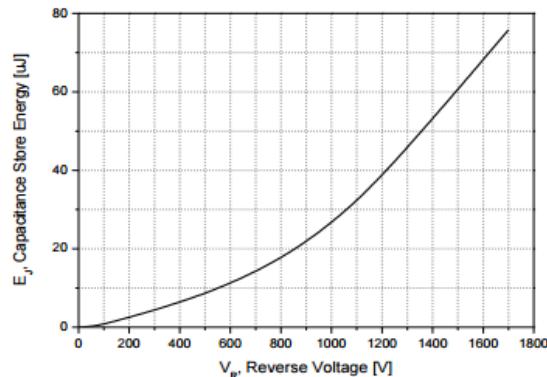


Figure 9. Capacitance Store Energy

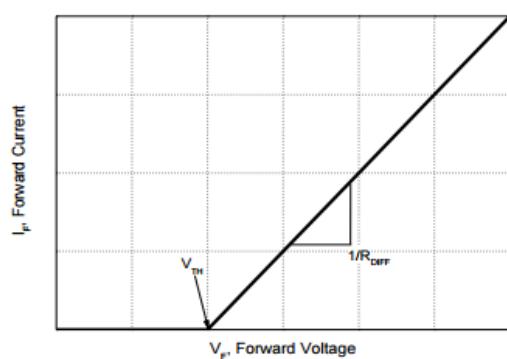


Figure 10. Equivalent Forward Current Curve

$$V_F = V_{TH} + R_{DIFF} \times I_F$$

Threshold Voltage (V_{TH})

$$V_{TH}(T_j) = -0.001 \times (T_j) + 0.930 \text{ [V]}$$

Differential Resistance (R_{DIFF})

$$R_{DIFF}(T_j) = A \times T_j^2 + B \times T_j + C \text{ [\Omega]}$$

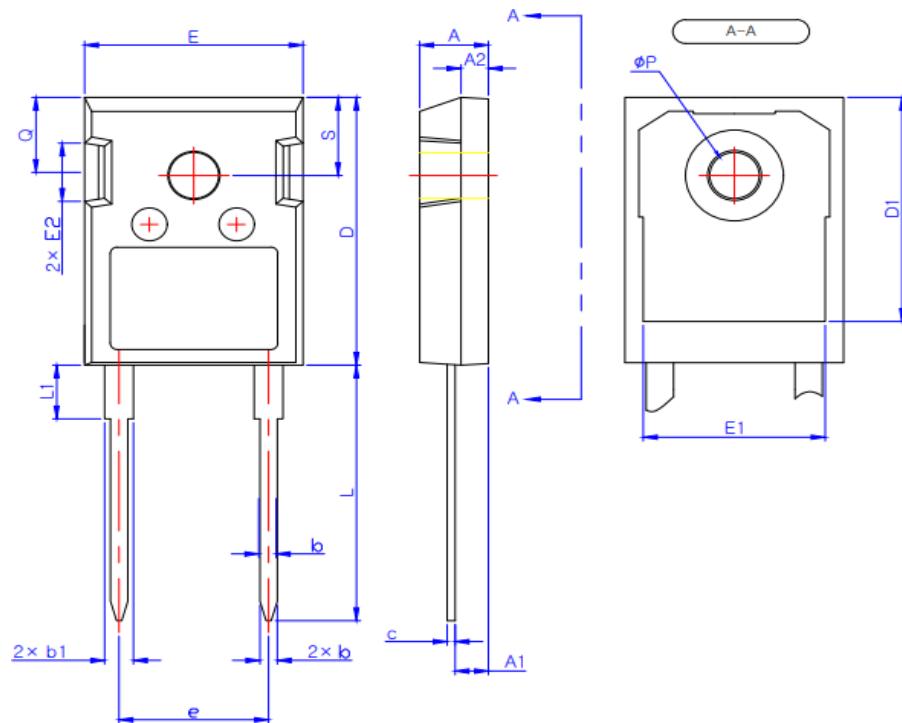
$$A = 1.70 \times 10^{-6}$$

$$B = 2.19 \times 10^{-4}$$

$$C = 4.75 \times 10^{-2}$$

[T_j [°C]; -55 °C ≤ T_j ≤ 175 °C; IF ≤ 10 A]

Package Information



SYMBOL	MIN	MAX
A	4.80	5.20
A1	2.29	2.54
A2	1.90	2.10
b	1.10	1.30
b1	1.91	2.20
c	0.50	0.70
D	20.80	21.34
D1	17.43	17.83
E	15.75	16.13
E1	13.06	13.46
E2	4.32	4.83
e	10.90 BSC	
L	19.85	20.25
L1	-	4.49
ϕP	3.55	3.65
Q	5.59	6.19
S	6.15 BSC	